1.8V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

IDT74AUCH16245

FEATURES:

- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- 1.8V Optimized
- 0.8V to 2.7V Operating Range
- · Inputs/outputs tolerant up to 3.6V
- Output drivers: ±9mA @ Vod = 2.3V
- · Supports hot insertion
- · Available in TSSOP, TVSOP, and VFBGA packages

APPLICATIONS:

- · High performance, low voltage communications systems
- · High performance, low voltage computing systems

DESCRIPTION:

This 16-bit bus transceiver is built using advanced CMOS technology. The AUCH16245 is designed specifically for asynchronous communications between data buses. The control function implementation minimizes external timing requirements.

This device can be used as one 16-bit transceiver or two 8-bit transceivers. It allows data transmission from A bus to B bus or from B bus to A bus, depending on the logic level at the direction-control (DIR) input. The output-enable $\overline{(OE)}$ input can be used to disable the device so that the buses are effectively isolated.

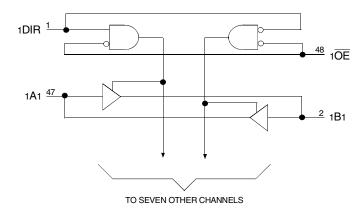
This device is fully specified for partial power-down applications using IOFF. The IOFF circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

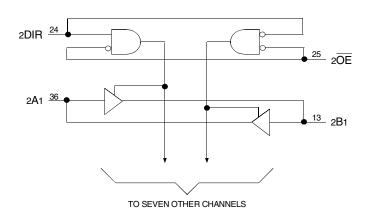
The AUCH16245 is designed with a \pm 9mA output driver. This driver is capable of driving a moderate load while maintaining speed performance.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to Vod through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The AUCH16245 data I/Os have bus-hold, which retains the last value whenever the I/O goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/pull-down resistors. Control inputs do not have bus-hold and should not be allowed to float.

FUNCTIONAL BLOCK DIAGRAM





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OCTOBER 2002

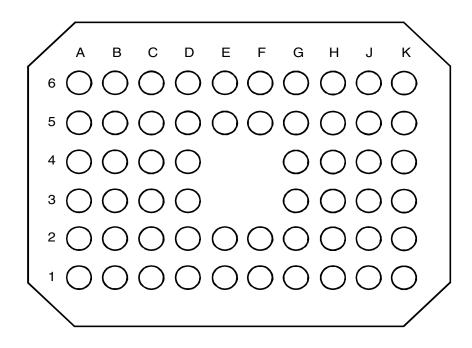
PINOUT CONFIGURATION

6	1 0E	1A2	1A4	1A6	1A8	2A1	2A3	2A5	2A7	2 0E
5	NC	1A1	1A3	1A5	1A7	2A2	2A4	2A6	2A8	NC
4	NC	GND	Vdd	GND			GND	Vdd	GND	NC
3	NC	GND	Vdd	GND			GND	Vdd	GND	NC
2	NC	1B1	1B3	1B5	1B7	2B2	2B4	2B6	2B8	NC
1	1DIR	1B2	1B4	1B6	1B8	2B1	2B3	2B5	2B7	2DIR
L	А	В	С	D	E	F	G	Н	J	K

VFBGA

NOTE: NC = No Internal Connection

56 BALL VFBGA PACKAGE LAYOUT



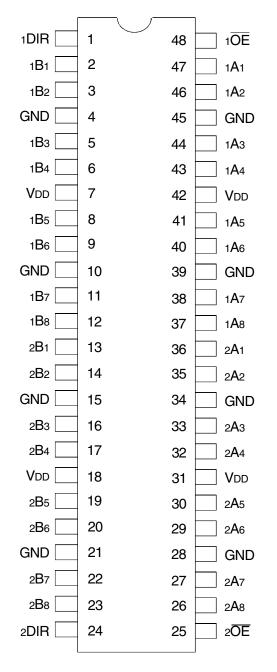
TOP VIEW

IDT74AUCH16245

1.8V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

INDUSTRIAL TEMPERATURE RANGE

PIN CONFIGURATION



TSSOP/ TVSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description		Max	Unit
VTERM	Terminal Voltage with Respec	t to GND	-0.5 to +3.6	V
	(all input and VDD terminals)			
VTERM	Terminal Voltage with Respec	t to GND	-0.5 to +3.6	V
	(any I/O or Output terminals ir	ı high-		
	impedance or power-off state)			
VTERM	Terminal Voltage with Respec	-0.5 to +3.6	V	
	(any I/O or Output terminals ir			
	low state)			
Tstg	Storage Temperature		-65 to +150	°C
Ιουτ	Continuous DC Output Currer	nt	±20	mA
Ік	Continuous Clamp Current	Vi > Vdd	+50	mA
		VI < 0	-50	
Іок	Continuous Clamp Current, V	-50	mA	
Idd	Continuous Current through	±100	mA	
Iss	each VDD or GND			

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, f = 1.0MHz, VDD = 2.5V)

Symbol	ool Parameter Conditions		Тур.	Max.	Unit
CIN	Input Capacitance ⁽¹⁾	VIN = 0V	3		pF
Ci/o	I/O Port Capacitance ⁽²⁾	VIN = 0V	8		pF

NOTES:

1. Applies to the Control Inputs.

2. Applies to ports A and B.

PINDESCRIPTION

Pin Names	Description			
xŌĒ	3-State Output Enable Inputs (Active Low)			
xDIR	Direction Control Inputs			
хАх	A Side Inputs or 3-State Outputs ⁽¹⁾			
хВх	B Side Inputs or 3-State Outputs ⁽¹⁾			

NOTE:

1. These pins have "bus-hold". All other pins are standard outputs, inputs, or I/Os.

FUNCTION TABLE (EACH 8-BIT SECTION)⁽¹⁾

Inp	outs			
xOE	xDIR	Outputs		
L	L	Bus B Data to Bus A		
L	Н	Bus A Data to Bus B		
Н	Х	Z		

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

Z = High-Impedance

RECOMMENDED OPERATING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	Test Conditions	Min.	Max.	Unit		
Vdd	Supply Voltage		0.8	2.7	V		
		VDD = 0.8V	Vdd	_			
		VDD = 1.1V to 1.3V	0.65 x Vdd	_	1		
VIH	Input HIGH Voltage Level	VDD = 1.4V to 1.6V	0.65 x Vdd	_	V		
		VDD = 1.65V to 1.95V	0.65 x Vdd	-	1		
		VDD = 2.3V to 2.7V	1.7	<u> </u>	1		
		VDD = 0.8V	-	0			
		VDD = 1.1V to 1.3V	-	0.35 x Vdd	1		
VIL	Input LOW Voltage Level	VDD = 1.4V to 1.6V	-	0.35 x Vdd	V		
		VDD = 1.65V to 1.95V	_	0.35 x Vdd			
		VDD = 2.3V to 2.7V	-	0.7			
VI	InputVoltage		0	2.7	V		
Vo	Output Voltage	Active State	0	Vdd	V		
		3-State	0	2.7			
		VDD = 0.8V	-	-0.7			
		VDD = 1.1V	_	-3			
Іон	HIGH Level Output Current	VDD = 1.4V	_	-5	mA		
		VDD = 1.65V	-	-8			
		VDD = 2.3V	_	-9			
		VDD = 0.8V	-	0.7			
		VDD = 1.1V	-	3	1		
Iol	LOW Level Output Current	VDD = 1.4V	-	5	mA		
		VDD = 1.65V	—	8	1		
		VDD = 2.3V	_	9			
$\Delta t/\Delta v$	Input Transition Rise or Fall Time		_	5	ns/V		
TA	Operating Free-Air Temperature		-40	+85	°C		

NOTE:

1. All unused inputs of the device must be held at V_{DD} or GND to ensure proper operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE⁽¹⁾

 ${\it Following \, Conditions \, Apply \, Unless \, Otherwise \, Specified:}$

Operating Conditions: $TA = -40^{\circ}C$ to $+85^{\circ}C$

Symbol	Parameter		Test Conditions		Min.	Тур.	Max.	Unit
Ін	Input HIGH or LOW Current	Data Inputs	VDD = 2.7V, VI = VDD or GND		—	—	±10	μA
lı.		Control Inputs		—	_	±5		
loff	Input/Output Power Off Leakage		VDD = 0V, VIN or VO $\leq 2.7V$		—	—	±10	μA
IOZH ⁽²⁾	High Impedance Output Current		VDD = 2.7V	Vo = Vdd	—	_	±10	μA
IOZL ⁽²⁾	(3-State Output Pins)			Vo = GND	—	_	±10	
Iddl	Quiescent Power Supply Cu	rrent	VDD = 0.8V to 2.7V		—	_	20	μA
Iddh			VIN = GND or VDD					
Iddz								

NOTES:

1. All unused inputs of the device must be held at V_DD or GND to ensure proper operation.

2. For the I/O ports, the parameters IozH and IozL include the input leakage current.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditi	ons	Min.	Тур.	Max.	Unit
		Vdd = 1.1V	VI = 0.8V	-10	-	-	
			VI = 0.35V	10	_		
Івнн	Bus-Hold Input Sustain Current	VDD = 1.4V	VI = 0.9V	-15	—	_	
IBHL			VI = 0.47V	15	_	_	
		VDD = 1.65V	VI = 1.07V	-20			μA
			VI = 0.57V	20			
		VDD = 2.3V	VI = 1.7V	-40	—	_	
			VI = 0.7V	40	—	_	
		Vdd = 1.3V		_	_	±125	
Івнно	Bus-Hold Input Overdrive Current	VDD = 1.6V	VI = 0 to VDD	_	—	±175	μA
Ibhlo		VDD = 1.95V		_	_	±250	
		VDD = 2.7V		—	—	±400	

NOTE:

1. Pins with Bus-hold are identified in the pin description.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditior	IS ⁽¹⁾	Min.	Тур.	Max.	Unit
Vон	Output HIGH Voltage	VDD = 0.8V - 2.7V	Іон = –100μА	Vdd - 0.1	—	-	
		VDD = 0.8V	Iон = -0.7mA	—	0.55	—	
		VDD = 1.1V ⁽²⁾	Iон = –3mA	0.8	—	—	V
		VDD = 1.4V ⁽³⁾	Iон = –5mA	1		_	
		$VDD = 1.65V^{(4)}$	Iон = –8mA	1.2	—	_	
		$VDD = 2.3V^{(5)}$	Iон = –9mA	1.8	_	—	
Vol	Output LOW Voltage	VDD = 0.8V - 2.7V	Іон = 100μА	—	_	0.2	
		VDD = 0.8V	IOL = 0.7mA	—	0.25	_	
		VDD = 1.1V ⁽²⁾	IOL = 3mA			0.3	V
		$VDD = 1.4V^{(3)}$	Iol = 5mA	—	—	0.4	
		VDD = 1.65V ⁽⁴⁾	Iol = 8mA	—	_	0.45	
		VDD = 2.3V ⁽⁵⁾	Iон = 9mA	_	_	0.6	

NOTES:

1. VIL and VIH must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS table for the appropriate VDD range. TA = -40°C to +85°C.

2. Demonstrates operation for nominal VDD = 1.2V.

3. Demonstrates operation for nominal VDD = 1.5V.

4. Demonstrates operation for nominal VDD = 1.8V.

5. Demonstrates operation for nominal VDD = 2.5V.

IDT74AUCH16245 1.8V CMOS16-BIT BUSTRANSCEIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

INDUSTRIAL TEMPERATURE RANGE

OPERATING CHARACTERISTICS, $TA = 25^{\circ}C$

Symbol	Parameter	Test Conditions	VDD = 0.8V	VDD = 1.2V	Vdd = 1.5V	Vdd = 1.8V	VDD = 2.5V	Unit
Cpd	Power Dissipation Capacitance Outputs Enabled	CL = 0pF f = 10MHz	22	23	24	25	29	pF
Cpd	Power Dissipation Capacitance Outputs Disabled	1 - 1010112	1	1	1	1	1	pF

SWITCHING CHARACTERISTICS⁽¹⁾

		VDD = 0.8V	VDD = 1.2V±0.1V		VDD = 1.5V±0.1V		VDD = 1.8V±0.15V			$VDD = 2.5V \pm 0.2V$		
Symbol	Parameter	Тур.	Min.	Max.	Min.	Max.	Min.	Тур.	Max.	Min.	Max.	Unit
t PLH	Propagation Delay	5.6	0.5	3.1	0.5	2	0.5	1.5	2	0.4	1.9	ns
t PHL	xAx to xBx or xBx to xAx											
tPZH	Output Enable Time	10	0.7	4.6	0.7	3.1	0.7	2.1	3.1	0.7	2.6	ns
tPZL	xOE to xAx or xBx											
tPHZ tPLZ	Output Disable Time xOE to xAx or xBx	12.8	0.8	6.8	0.8	5	0.8	3.4	4.8	0.5	2.9	ns

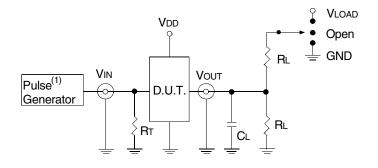
NOTE:

1. See TEST CIRCUITS AND WAVEFORMS. TA = -40° C to $+85^{\circ}$ C.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS⁽¹⁾

Symbol	VDD = 0.8V	$VDD = 1.2V \pm 0.1V$	$V_{DD} = 1.5V \pm 0.1V$	VDD = 1.8V±0.15V	$VDD = 2.5V \pm 0.2V$	Unit
VLOAD	2xVdd	2xVdd	2xVdd	2xVdd	2xVdd	V
VT	Vdd/2	Vdd/2	Vdd/2	Vdd/2	Vdd/2	V
VLZ	100	100	100	150	150	mV
VHZ	100	100	100	150	150	mV
R∟	2	2	2	1	0.5	KΩ
CL	15	15	15	30	30	pF



Test Circuits for All Outputs

DEFINITIONS:

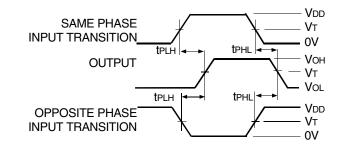
CL = Load capacitance: includes jig and probe capacitance.

 $\mathsf{R} \mathsf{T} = \mathsf{Termination}$ resistance: should be equal to $\mathsf{Z}\mathsf{o}\mathsf{u}\mathsf{T}$ of the Pulse Generator. NOTE:

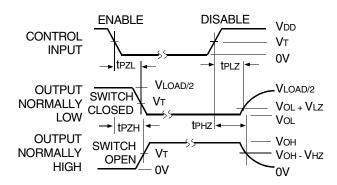
1. Pulse Generator for All Pulses: Rate \leq 10MHz; Slew Rate \geq 1V/ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Vload
Disable High Enable High	GND
All Other Tests	Open



Propagation Delay

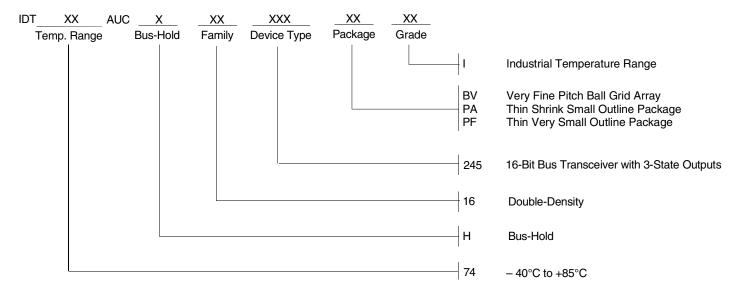


NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

ORDERING INFORMATION





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